

SMALL SIGNAL SCHOTTKY DIODE

PRELIMINARY DATASHEET

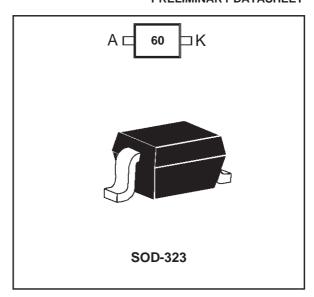
FEATURES AND BENEFITS

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD VOLTAGE DROP
- EXTREMELY FAST SWITCHING
- SURFACE MOUNTED DEVICE

DESCRIPTION

Schottky barrier diode encapsulated in a SOD-323 small SMD package.

This device is intended for use in portable equipments. It is suited for DC to DC converters, step-up conversion and power management.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
VRRM	Repetitive peak reverse voltage	10	V
I _{F(AV)}	Average forward current	3	Α
I _{FSM}	Surge non repetitive forward current	5	Α
P _{tot}	Power Dissipation	230	mW
T _{stg}	Storage temperature range	- 65 to +150	°C
Tj	Maximum operating junction temperature *	150	°C
TL	Maximum temperature for soldering during 10s	260	°C

^{* :} $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th (j-a)}	Junction to ambient (*)	400	°C/W

^(*) Mounted on epoxy board with recommended pad layout.

June 1999 - Ed: 2A

BAT60J

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Tests Conditions	Tests conditions		Min.	Тур.	Max.	Unit
V _F *	Forward voltage drop	Tj = 25°C	I _F = 1 mA		0.28	0.32	V
			IF = 100 mA		0.35	0.40	
			I _F = 1 A		0.53	0.58	
I _R **	Reverse leakage current	Tj = 25°C	V _R = 5 V		1	3	μΑ
		Tj = 25°C	V _R = 8 V		1.3	4	
		Tj = 80°C	V _R = 8 V		73	220	

Pulse test: $* tp = 380 \mu s$, $\delta < 2\%$

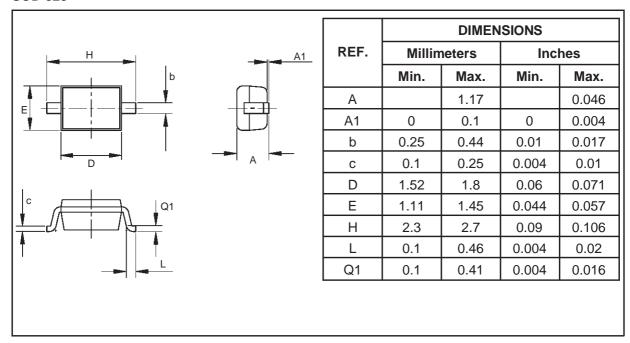
DYNAMIC CHARACTERISTICS

Symbol	Parameters	Tests conditions	Min.	Тур.	Max.	Unit
С	Diode capacitance	V _R = 5 V F = 1 MHz Tj = 25°C		35		pF

^{**} $tp = 5ms, \delta < 2\%$

PACKAGE MECHANICAL DATA

SOD-323



MARKING

Туре	Marking	Package	Weight	Base qty	Delivery mode
BAT60J	60	SOD-323	0.005 g.	3000	Tape & reel

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